

# PM200CVA060

FLAT-BASE TYPE  
INSULATED PACKAGE

## PM200CVA060



### FEATURE

- 3φ 200A, 600V Current-sense IGBT for 20kHz switching
- Monolithic gate drive & protection logic
- Detection, protection & status indication circuits for over-current, short-circuit, over-temperature & under-voltage (P-Fo available from upper leg devices)
- Acoustic noise-less 22kW class inverter application
- UL Recognized

Yellow Card No. E80276(N)

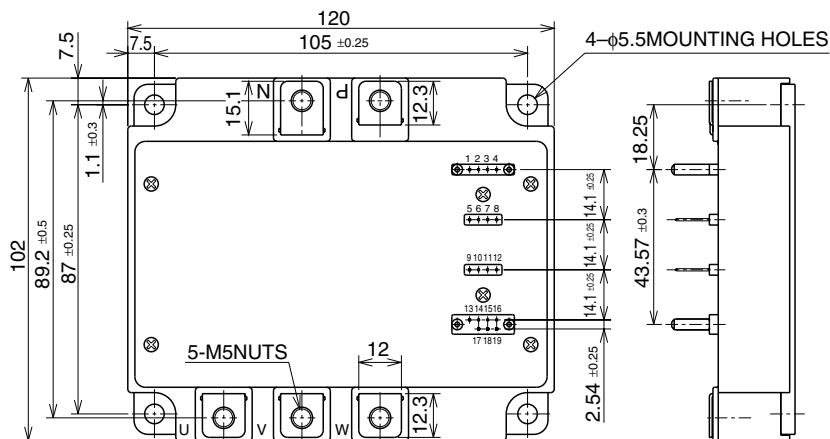
File No. E80271

## APPLICATION

General purpose inverter, servo drives and other motor controls

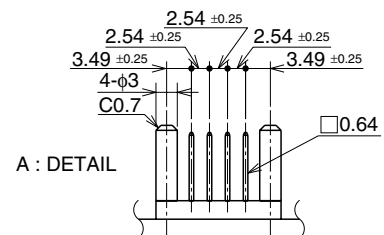
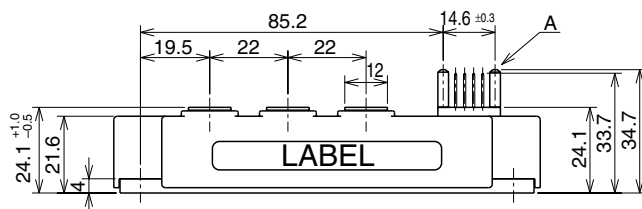
## PACKAGE OUTLINES

Dimensions in mm



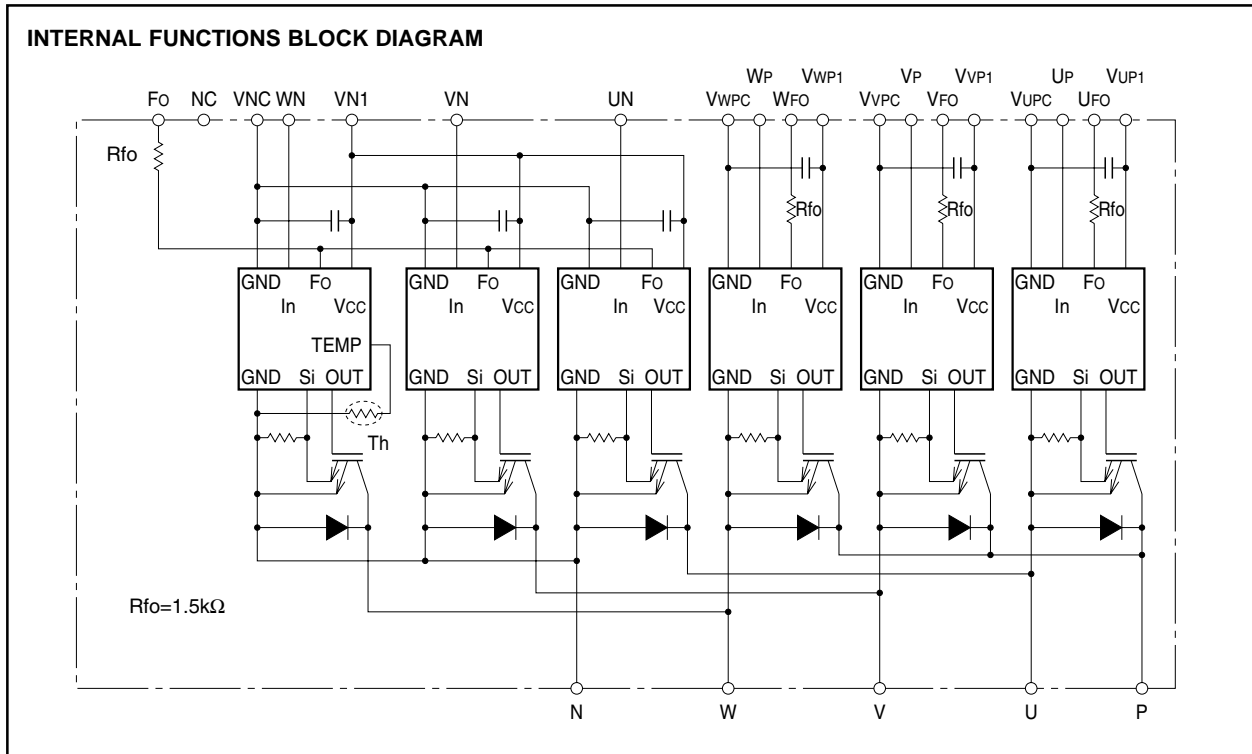
### TERMINAL CODE

- |         |          |         |
|---------|----------|---------|
| 1. WFO  | 8. VVP1  | 15. VNC |
| 2. VWPC | 9. UFo   | 16. VN1 |
| 3. WP   | 10. VUPC | 17. UN  |
| 4. VWP1 | 11. UP   | 18. VN  |
| 5. VFO  | 12. VUP1 | 19. WN  |
| 6. VVPC | 13. NC   |         |
| 7. VP   | 14. Fo   |         |



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**MAXIMUM RATINGS** ( $T_j = 25^\circ\text{C}$ , unless otherwise noted)

**INVERTER PART**

Symbol	Parameter	Condition	Ratings	Unit
$V_{CES}$	Collector-Emitter Voltage	$V_D = 15\text{V}$ , $V_{CIN} = 15\text{V}$	600	V
$\pm I_C$	Collector Current	$T_C = 25^\circ\text{C}$	200	A
$\pm I_{CP}$	Collector Current (Peak)	$T_C = 25^\circ\text{C}$	400	A
$P_C$	Collector Dissipation	$T_C = 25^\circ\text{C}$	541	W
$T_j$	Junction Temperature		$-20 \sim +150$	$^\circ\text{C}$

**CONTROL PART**

Symbol	Parameter	Condition	Ratings	Unit
$V_D$	Supply Voltage	Applied between : $V_{UP1}-V_{UPC}$ $V_{VP1}-V_{VPC}$ , $V_{WP1}-V_{WPC}$ , $V_{N1}-V_{NC}$	20	V
$V_{CIN}$	Input Voltage	Applied between : $U_P-V_{UPC}$ , $V_P-V_{VPC}$ , $W_P-V_{WPC}$ $U_N \cdot V_N \cdot W_N-V_{NC}$	20	V
$V_{FO}$	Fault Output Supply Voltage	Applied between : $U_{FO}-V_{UPC}$ , $V_{FO}-V_{VPC}$ , $W_{FO}-V_{WPC}$ $F_O-V_{NC}$	20	V
$I_{FO}$	Fault Output Current	Sink current at $U_{FO}$ , $V_{FO}$ , $W_{FO}$ and $F_O$ terminal	20	mA

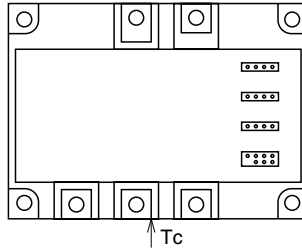
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## TOTAL SYSTEM

Symbol	Parameter	Condition	Ratings	Unit
V <sub>CC(Prot)</sub>	Supply Voltage Protected by SC	V <sub>D</sub> = 13.5 ~ 16.5V, Inverter Part, T <sub>j</sub> = 125°C Start	400	V
V <sub>CC(surge)</sub>	Supply Voltage (Surge)	Applied between : P-N, Surge value or without switching	500	V
T <sub>c</sub>	Module Case Operating Temperature	(Note-1)	-20 ~ +100	°C
T <sub>stg</sub>	Storage Temperature		-40 ~ +125	°C
V <sub>iso</sub>	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base, AC 1 min.	2500	V <sub>rms</sub>

(Note-1) T<sub>c</sub> measurement point is below. (3mm depth at the center of the side of base plate)



## ELECTRICAL CHARACTERISTICS (T<sub>j</sub> = 25°C, unless otherwise noted)

### INVERTER PART

Symbol	Parameter	Test Condition	Limits			Unit	
			Min.	Typ.	Max.		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	V <sub>D</sub> = 15V, I <sub>c</sub> = 200A V <sub>CIN</sub> = 0V	T <sub>j</sub> = 25°C	—	2.35	2.80	V
			T <sub>j</sub> = 125°C	—	2.55	3.05	
V <sub>EC</sub>	FWDI Forward Voltage	-I <sub>c</sub> = 200A, V <sub>D</sub> = 15V, V <sub>CIN</sub> = 15V	—	2.20	3.30	V	
t <sub>on</sub>	Switching Time	V <sub>D</sub> = 15V, V <sub>CIN</sub> = 0V↔15V V <sub>CC</sub> = 300V, I <sub>c</sub> = 200A T <sub>j</sub> = 125°C Inductive Load (upper and lower arm)	—	0.4	0.8	2.1	μs
t <sub>tr</sub>			—	0.2	0.3		
t <sub>c(on)</sub>			—	0.3	1.1		
t <sub>off</sub>			—	1.8	2.9		
t <sub>c(off)</sub>			—	0.6	1.2		
I <sub>CES</sub>	Collector-Emitter Cutoff Current	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>CIN</sub> = 15V	T <sub>j</sub> = 25°C	—	—	1	mA
			T <sub>j</sub> = 125°C	—	—	10	

### CONTROL PART

Symbol	Parameter	Test Condition	Limits			Unit	
			Min.	Typ.	Max.		
I <sub>D</sub>	Circuit Current	V <sub>D</sub> = 15V, V <sub>CIN</sub> = 15V	V <sub>N1</sub> -V <sub>N2</sub>	—	40	55	mA
			V*P1-V*PC	—	13	18	
V <sub>th(ON)</sub>	Input ON Threshold Voltage	Applied between : U <sub>P</sub> -V <sub>U</sub> PC, V <sub>P</sub> -V <sub>V</sub> PC, W <sub>P</sub> -V <sub>W</sub> PC U <sub>N</sub> • V <sub>N</sub> • W <sub>N</sub> -V <sub>N2</sub>	1.2	1.5	1.8	V	
V <sub>th(OFF)</sub>	Input OFF Threshold Voltage		1.7	2.0	2.3		
SC	Short Circuit Trip Level	-20 ≤ T <sub>j</sub> ≤ 125°C, V <sub>D</sub> = 15V	310	—	—	A	
t <sub>off(SC)</sub>	Short Circuit Current Delay Time	V <sub>D</sub> = 15V	—	10	—	μs	
OT	Over Temperature Protection	Base-plate Temperature detection, V <sub>D</sub> = 15V	Trip level	111	118	125	°C
			Reset level	—	100	—	
UV	Supply Circuit Under-Voltage Protection	-20 ≤ T <sub>j</sub> ≤ 125°C	Trip level	11.5	12.0	12.5	V
			Reset level	—	12.5	—	
I <sub>FO(H)</sub>	Fault Output Current	V <sub>D</sub> = 15V, V <sub>FO</sub> = 15V (Note-2)	—	—	0.01	mA	
I <sub>FO(L)</sub>			—	10	15		
t <sub>FO</sub>	Minimum Fault Output Pulse Width	V <sub>D</sub> = 15V (Note-2)	1.0	1.8	—	ms	

(Note-2) Fault output is given only when the internal SC, OT & UV protection.  
 Fault output of OT protection operate by lower arm  
 Fault output of OT, UV protection given pulse while over level.

**PM200CVA060**FLAT-BASE TYPE  
INSULATED PACKAGE**THERMAL RESISTANCES**

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
R <sub>th(j-c)Q</sub>	Junction to case Thermal Resistances	Inverter IGBT part (per 1/6 module)	—	—	0.231	°C/W
R <sub>th(j-c)F</sub>		Inverter FWDi part (per 1/6 module)	—	—	0.35	
R <sub>th(c-f)</sub>	Contact Thermal Resistance	Case to fin, Thermal grease applied (per 1 module)	—	—	0.022	

**MECHANICAL RATINGS AND CHARACTERISTICS**

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
—	Mounting torque	Mounting part screw : M5	2.5	3.0	3.5	N • m
—	Mounting torque	Main terminal screw : M5	2.5	3.0	3.5	N • m
—	Weight		—	730	—	g

**RECOMMENDED CONDITIONS FOR USE**

Symbol	Parameter	Test Condition	Recommended value	Unit
V <sub>CC</sub>	Supply Voltage	Applied across P-N terminals	≤ 400	V
V <sub>D</sub>	Control Supply Voltage	Applied between : V <sub>UP1</sub> -V <sub>UPC</sub> , V <sub>VP1</sub> -V <sub>VPC</sub> V <sub>WP1</sub> -V <sub>WPC</sub> , V <sub>N1</sub> -V <sub>NVC</sub> (Note-3)	15 ± 1.5	V
V <sub>CIN(ON)</sub>	Input ON Voltage	Applied between : U <sub>P</sub> -V <sub>UPC</sub> , V <sub>P</sub> -V <sub>VPC</sub> , W <sub>P</sub> -V <sub>WPC</sub> U <sub>N</sub> • V <sub>N</sub> • W <sub>N</sub> -V <sub>NVC</sub>	≤ 0.8	V
V <sub>CIN(OFF)</sub>	Input OFF Voltage		≥ 4.0	
t <sub>dead</sub>	Arm Shoot-through Blocking Time	For IPM's each input signals	≥ 2.5	μs
f <sub>PWM</sub>	PWM Input Frequency	Using Application Circuit input signal of IPM, 3φ Sinusoidal PWM VVVF inverter	≤ 20	kHz

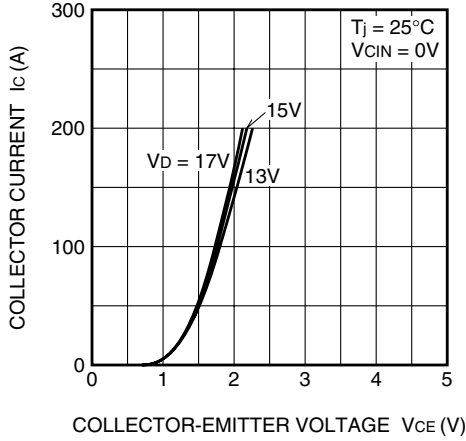
(Note-3) With ripple satisfying the following conditions dv/dt swing ≤ ±5V/μs, Variation ≤ 2V peak to peak

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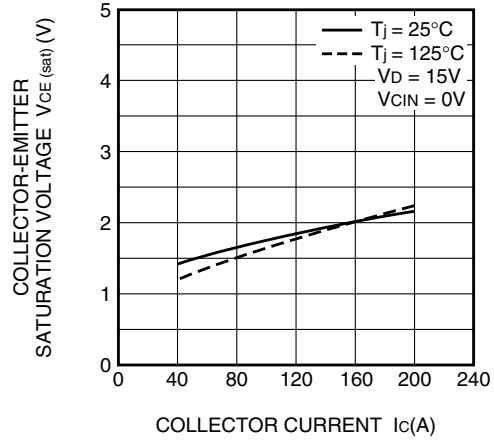
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## PERFORMANCE CURVES

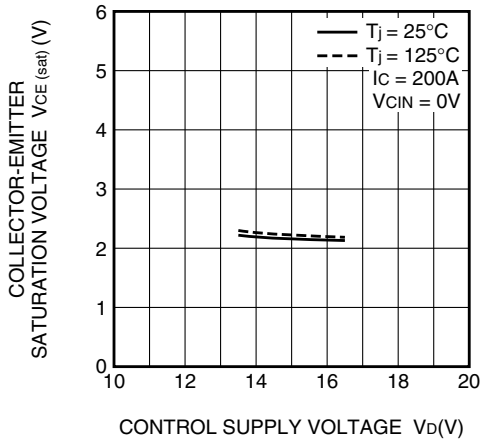
**OUTPUT CHARACTERISTICS (TYPICAL)**



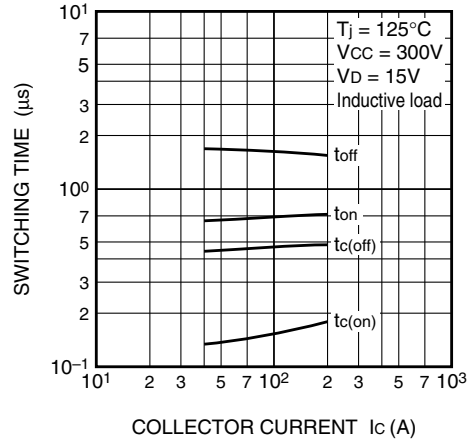
**COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)**



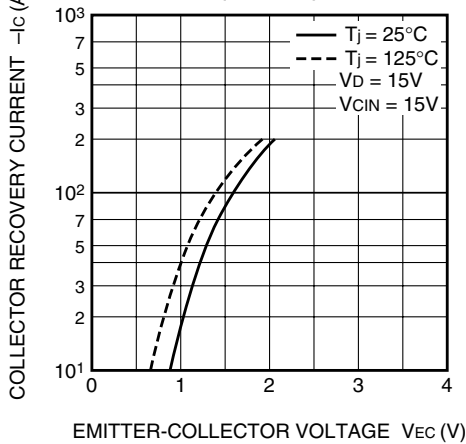
**COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)**



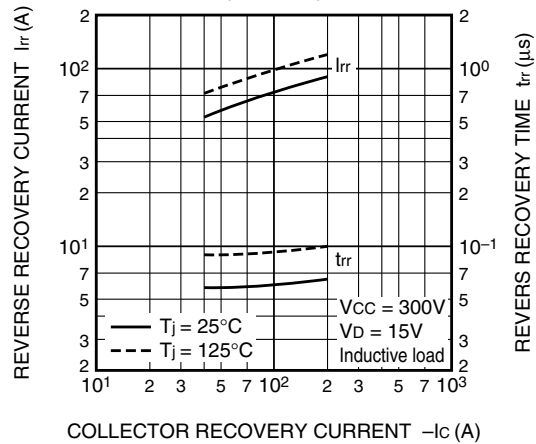
**SWITCHING CHARACTERISTICS (TYPICAL)**



**DIODE FORWARD CHARACTERISTICS (TYPICAL)**



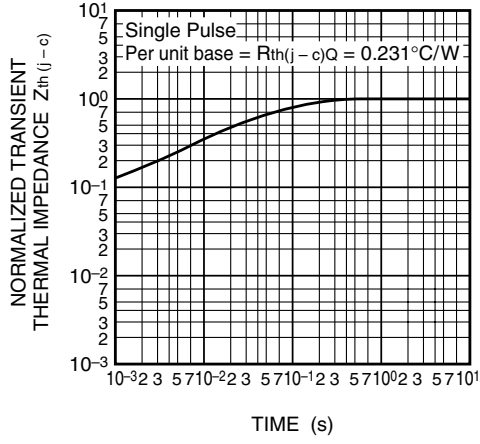
**DIODE REVERSE RECOVERY CHARACTERISTICS (TYPICAL)**



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**TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
(IGBT per 1 element)**



**TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
(FWDi per 1 element)**

